

TL750M, TL751M LOW-DROPOUT VOLTAGE REGULATORS

SLVS021F – JANUARY 1988 – REVISED AUGUST 1998

- Very Low Dropout Voltage, Less Than 0.6 V at 750 mA
- Low Quiescent Current
- TTL- and CMOS-Compatible Enable on TL751M Series
- 60-V Load-Dump Protection
- Overvoltage Protection
- Internal Thermal Overload Protection
- Internal Overcurrent Limiting Circuitry

description

The TL750M and TL751M series are low-dropout positive voltage regulators specifically designed for battery-powered systems. The TL750M and TL751M incorporate on-board overvoltage and current-limit protection circuitry to protect the TL75xM devices and the regulated system. Both series are fully protected against 60-V load-dump and reverse battery conditions. Extremely low quiescent current, even during full-load conditions, makes the TL750M and TL751M series ideal for standby power systems.

The TL750M series of fixed-output voltage regulators offers 5-V, 8-V, 10-V, and 12-V options available in 3-lead KC (TO-220AB) and KTE plastic packages.

The TL751M series of fixed-output voltage regulators also offers 5-V, 8-V, 10-V, and 12-V options with the addition of an enable input. The enable input gives the designer complete control over power up, allowing sequential power up or emergency shutdown. When taken high, the enable input places the regulator output in a high-impedance state. The enable input is completely TTL- and CMOS-compatible. The TL751M series is offered in 5-lead KTG plastic packages.

The TL750MxxC and TL751MxxC are characterized for operation from 0°C to 125°C virtual junction temperature, and the TL750MxxQ and TL751MxxQ series are characterized for operation from –40°C to 125°C virtual junction temperature. The TL751M05M and TL751M12M are characterized for operation over the full military temperature range of –55°C to 125°C.

AVAILABLE OPTIONS

T _J	V _O TYP (V)	PACKAGED DEVICES						CHIP FORM (Y)
		CHIP CARRIER (FK)	CERAMIC DIP (JG)	HEAT-SINK MOUNTED (3-PIN) (KC)	PLASTIC FLANGE MOUNT (KTE)†	PLASTIC FLANGE MOUNT (KTG)†	PLASTIC FLANGE MOUNT (KTP)†	
0°C to 125°C	5	—	—	TL750M05CKC	TL750M05CKTE	TL751M05CKTG	TL750M05CKTP	TL750M05Y
	8	—	—	TL750M08CKC	TL750M08CKTE	TL751M08CKTG	TL750M08CKTP	TL750M08Y
	10	—	—	TL750M10CKC	TL750M10CKTE	TL751M10CKTG	TL750M10CKTP	TL750M10Y
	12	—	—	TL750M12CKC	TL750M12CKTE	TL751M12CKTG	TL750M12CKTP	TL750M12Y
–40°C to 125°C	5	—	—	TL750M05QKC	TL750M05QKTE	TL751M05QKTG	—	—
	8	—	—	TL750M08QKC	TL750M08QKTE	TL751M08QKTG	—	—
	10	—	—	TL750M10QKC	TL750M10QKTE	TL751M10QKTG	—	—
	12	—	—	TL750M12QKC	TL750M12QKTE	TL751M12QKTG	—	—
–55°C to 125°C	5	TL751M05MFK	TL751M05MJG	—	—	—	—	—
	12	TL751M12MFK	TL751M12MJG	—	—	—	—	—

† The KTE and KTG packages also are available taped and reeled. The KTP is only available taped and reeled.



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

 **TEXAS
INSTRUMENTS**

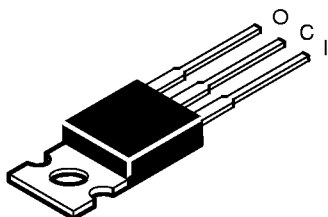
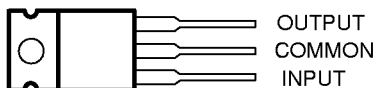
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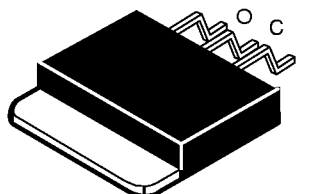
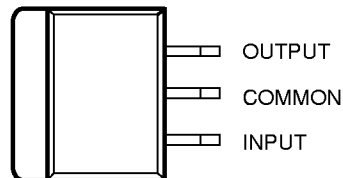
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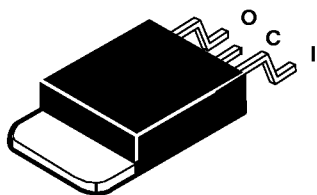
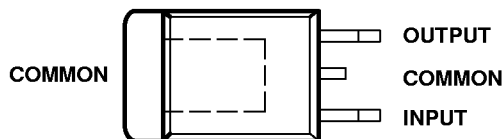
TL750M . . . 3-LEAD KC (TO-200AB) PACKAGE†
(TOP VIEW)



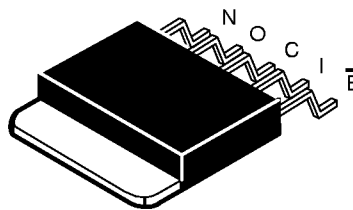
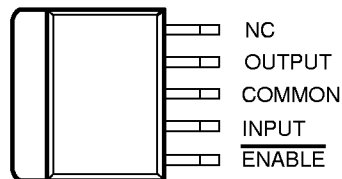
TL750M . . . 3-LEAD KTE PACKAGE†
(TOP VIEW)



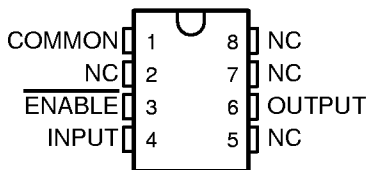
TL750M . . . KTP PACKAGE†
(TOP VIEW)



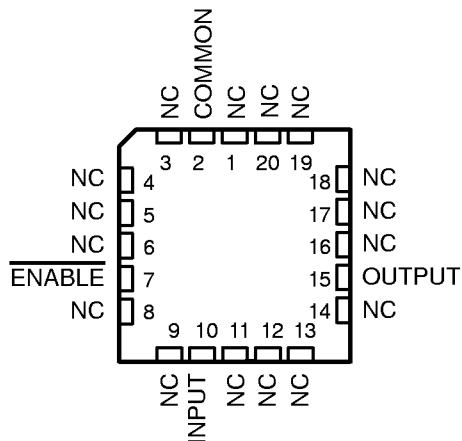
TL751M . . . 5-LEAD KTG PACKAGE†
(TOP VIEW)



TL751M . . . JG PACKAGE
(TOP VIEW)



TL751M . . . FK PACKAGE
(TOP VIEW)



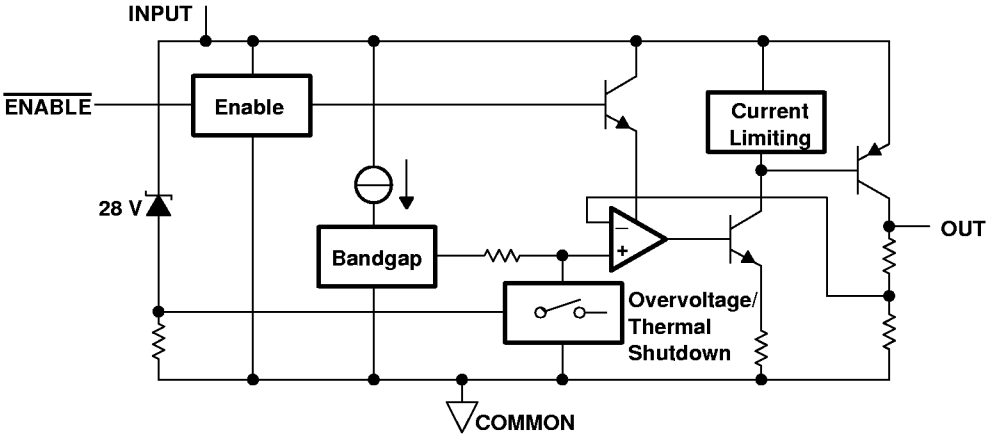
NC – No internal connection

† The common terminal is in electrical contact with the mounting base.

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TL751Mxx functional block diagram



DEVICE COMPONENT COUNT	
Transistors	46
Diodes	14
Resistors	44
Capacitors	4
JFET	1
Tunnels (emitter R)	2

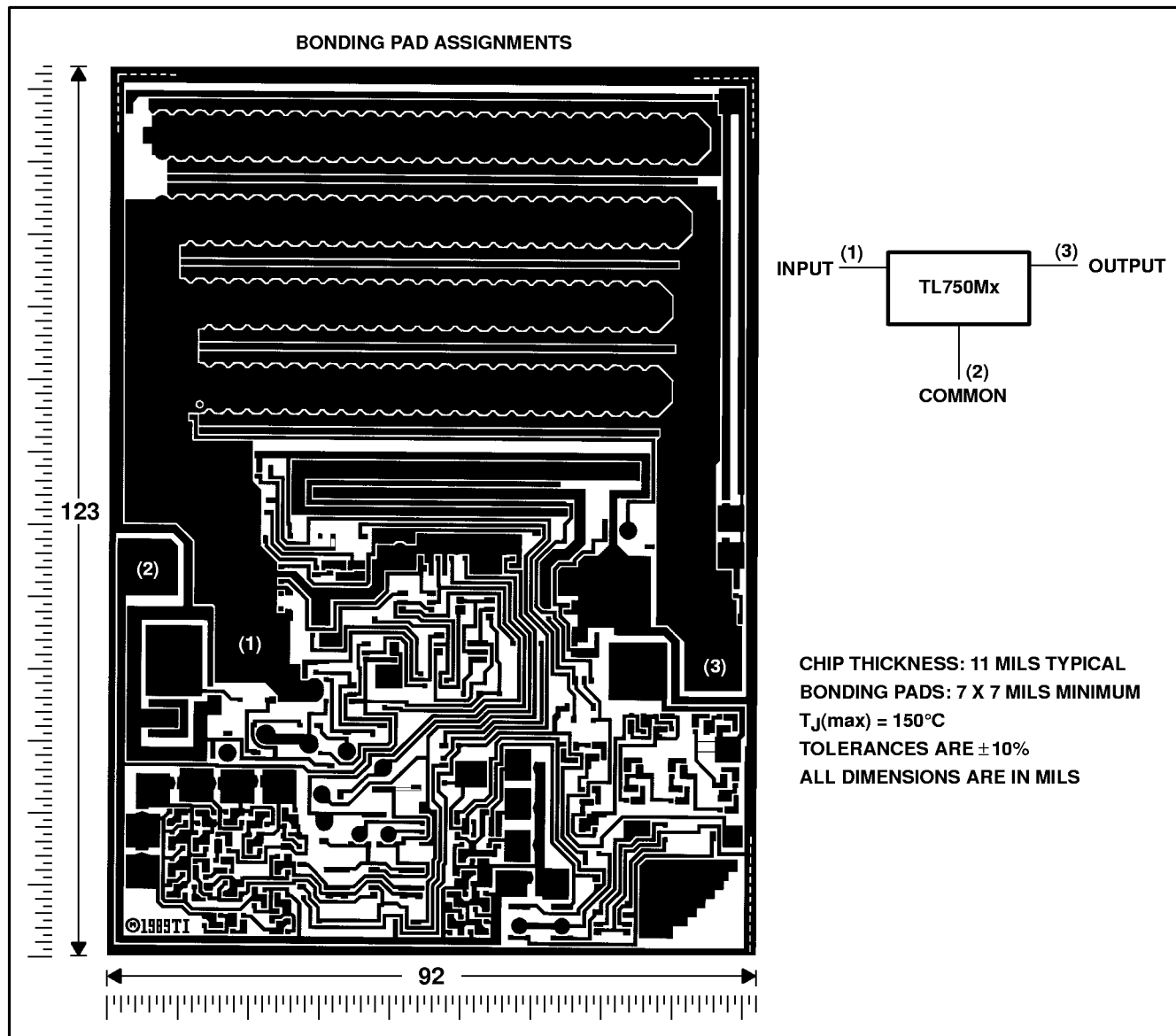


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TL750MxxY chip information

This chip, when properly assembled, displays characteristics similar to the TL750MxxC. Thermal compression or ultrasonic bonding can be used on the doped-aluminum bonding pads. The chip can be mounted with conductive epoxy or a gold-silicon preform.



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absolute maximum ratings over virtual junction temperature range (unless otherwise noted)†

Continuous input voltage	26 V
Transient input voltage (see Figure 5)	60 V
Continuous reverse input voltage	–15 V
Transient reverse input voltage: t = 100 ms	–50 V
Continuous total power dissipation at (or below) $T_A = 25^\circ\text{C}$	See Dissipation Rating Tables
Continuous total power dissipation at (or below) $T_C = 40^\circ\text{C}$:	
FK Package	5.5 W
JG Package	3.9 W
All other packages (see Note 1) ...	See Dissipation Rating Tables
Operating free-air (T_A) case (T_C) or virtual-junction (T_J) temperature range	–40°C to 150°C
Storage temperature range, T_{stg}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: For operation above $T_A = 25^\circ\text{C}$ and $T_C = 40^\circ\text{C}$, refer to Figures 1 and 2. To avoid exceeding the design maximum virtual junction temperature, these ratings should not be exceeded. Due to variation in individual device electrical characteristics and thermal resistance, the built-in thermal overload protection may be activated at power levels slightly above or below the rated dissipation.

DISSIPATION RATING TABLE — FREE-AIR TEMPERATURE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 105^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
FK	1920 mW	15.4 mW/°C	1227 mW	688 mW	380 mW
JG	1050 mW	8.4 mW/°C	672 mW	378 mW	210 mW
KC	2000 mW	16 mW/°C	1280 mW	720 mW	400 mW
KTE/KTG	1900 mW	15.2 mW/°C	1216 mW	684 mW	380 mW
KTP	1800 mW	14.5 mW/°C	1147 mW	653 mW	363 mW

DISSIPATION RATING TABLE — CASE TEMPERATURE

PACKAGE	$T_C \leq 90^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_C = 90^\circ\text{C}$	$T_C = 125^\circ\text{C}$ POWER RATING
KC	15000 mW	250 mW/°C	6250 mW
KTE/KTG	14300 mW	238 mW/°C	5970 mW
KTP	13000 mW	217 mW/°C	5417 mW



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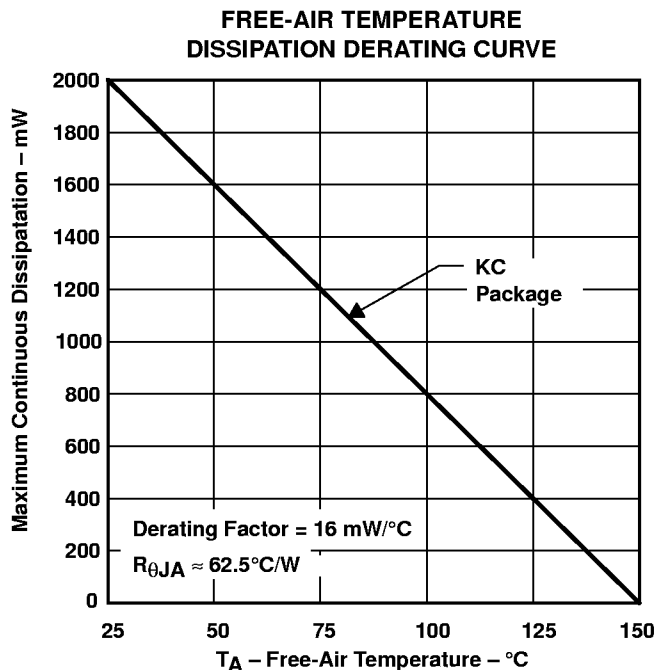


Figure 1

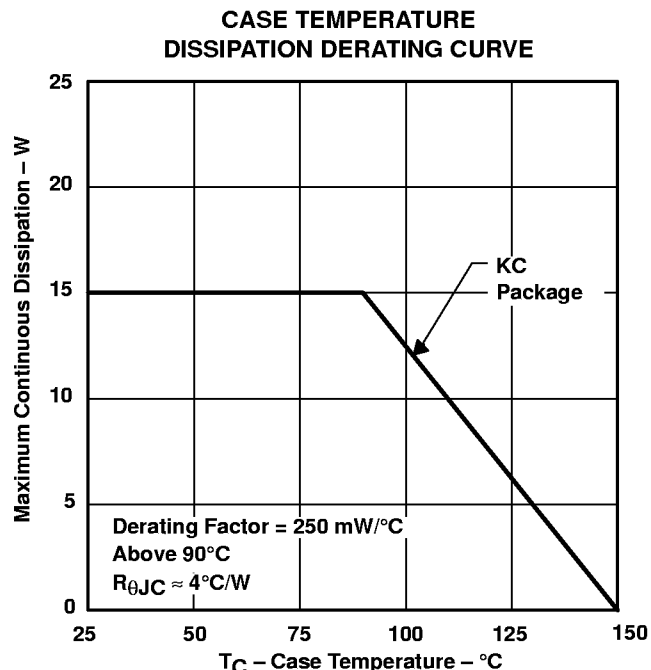


Figure 2

recommended operating conditions over recommended virtual junction temperature range

		MIN	MAX	UNIT
Input voltage range, V_I	TL75xM05	6	26	V
	TL75xM08	9	26	
	TL75xM10	11	26	
	TL75xM12	13	26	
High-level $\overline{\text{ENABLE}}$ input voltage, V_{IH}	TL751Mxx	2	15	V
Low-level $\overline{\text{ENABLE}}$ input voltage, V_{IL}	TL751Mxx	0	0.8	
Output current range, I_O	TL75xMxxC, TL75xMxxQ		750	mA
	TL751MxxM		480	mA
Operating virtual junction temperature range, T_J	TL75xMxxC	0	125	°C
	TL75xMxxQ	-40	125	
	TL75xMxxM	-55	125	

electrical characteristics, $V_I = 14\text{ V}$, $I_O = 300\text{ mA}$, $T_J = 25^\circ\text{C}$

PARAMETER	TL751Mxxx			UNIT
	MIN	TYP	MAX	
Response time, $\overline{\text{ENABLE}}$ to output		50		μs



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electrical characteristics, $V_I = 14\text{ V}$, $I_O = 300\text{ mA}$, $\overline{\text{ENABLE}}$ at 0 V for TL751M05, $T_J = 25^\circ\text{C}$ (unless otherwise noted) (see Note 2)

PARAMETER	TEST CONDITIONS	TL750M05C, TL751M05C TL750M05Q, TL751M05Q			UNIT
		MIN	TYP	MAX	
Output voltage	$T_J = 25^\circ\text{C}$	4.95	5	5.05	V
	$T_J = \text{MIN to MAX}^\dagger$	4.9		5.1	
Input voltage regulation	$V_I = 9\text{ V to }16\text{ V}, I_O = 250\text{ mA}$		10	25	mV
	$V_I = 6\text{ V to }26\text{ V}, I_O = 250\text{ mA}$		12	50	
Ripple rejection	$V_I = 8\text{ V to }18\text{ V}, f = 120\text{ Hz}$	50	55		dB
Output voltage regulation	$I_O = 5\text{ mA to }750\text{ mA}$		20	50	mV
Dropout voltage	$I_O = 500\text{ mA}$			0.5	V
	$I_O = 750\text{ mA}$			0.6	
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		500		μV
Bias current	$I_O = 750\text{ mA}$		60	75	mA
	$I_O = 10\text{ mA}$			5	
Bias current (TL751M05C and TL751M05Q only)	$\overline{\text{ENABLE}} V_{IH} \geq 2\text{ V}$			200	μA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

NOTE 2: Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1- μF capacitor across the input and a 10- μF tantalum capacitor on the output with equivalent series resistance within the guidelines shown in Figure 3.

electrical characteristics, $V_I = 14\text{ V}$, $I_O = 300\text{ mA}$, $\overline{\text{ENABLE}}$ at 0 V for TL751M08, $T_J = 25^\circ\text{C}$ (unless otherwise noted) (see Note 2)

PARAMETER	TEST CONDITIONS	TL750M08x, TL751M08x			UNIT
		MIN	TYP	MAX	
Output voltage	$T_J = 25^\circ\text{C}$	7.92	8	8.08	V
	$T_J = \text{MIN to MAX}^\dagger$	7.84		8.16	
Input voltage regulation	$V_I = 10\text{ V to }17\text{ V}, I_O = 250\text{ mA}$		12	40	mV
	$V_I = 9\text{ V to }26\text{ V}, I_O = 250\text{ mA}$		15	68	
Ripple rejection	$V_I = 11\text{ V to }21\text{ V}, f = 120\text{ Hz}$	50	55		dB
Output voltage regulation	$I_O = 5\text{ mA to }750\text{ mA}$		24	80	mV
Dropout voltage	$I_O = 500\text{ mA}$			0.5	V
	$I_O = 750\text{ mA}$			0.6	
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		500		μV
Bias current	$I_O = 750\text{ mA}$		60	75	mA
	$I_O = 10\text{ mA}$			5	
Bias current (TL751Mxx only)	$\overline{\text{ENABLE}} V_{IH} \geq 2\text{ V}$			200	μA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

NOTE 2: Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1- μF capacitor across the input and a 10- μF tantalum capacitor on the output with equivalent series resistance within the guidelines shown in Figure 3.



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electrical characteristics, $V_I = 14\text{ V}$, $I_O = 300\text{ mA}$, $\overline{\text{ENABLE}}$ at 0 V for TL751M10, $T_J = 25^\circ\text{C}$ (unless otherwise noted) (see Note 2)

PARAMETER	TEST CONDITIONS	TL750M10x, TL751M10x			UNIT
		MIN	TYP	MAX	
Output voltage	$T_J = 25^\circ\text{C}$	9.9	10	10.1	V
	$T_J = \text{MIN to MAX}^\dagger$	9.8		10.2	
Input voltage regulation	$V_I = 12\text{ V to }18\text{ V}, I_O = 250\text{ mA}$		15	43	mV
	$V_I = 11\text{ V to }26\text{ V}, I_O = 250\text{ mA}$		20	75	
Ripple rejection	$V_I = 13\text{ V to }23\text{ V}, f = 120\text{ Hz}$	50	55		dB
Output voltage regulation	$I_O = 5\text{ mA to }750\text{ mA}$		30	100	mV
Dropout voltage	$I_O = 500\text{ mA}$			0.5	V
	$I_O = 750\text{ mA}$			0.6	
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		1000		μV
Bias current	$I_O = 750\text{ mA}$		60	75	mA
	$I_O = 10\text{ mA}$			5	
Bias current (TL751Mxx only)	$\overline{\text{ENABLE}} V_{IH} \geq 2\text{ V}$			200	μA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

NOTE 2: Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1- μF capacitor across the input and a 10- μF tantalum capacitor on the output with equivalent series resistance within the guidelines shown in Figure 3.

electrical characteristics, $V_I = 14\text{ V}$, $I_O = 300\text{ mA}$, $\overline{\text{ENABLE}}$ at 0 V for TL751M12, $T_J = 25^\circ\text{C}$ (unless otherwise noted) (see Note 2)

PARAMETER	TEST CONDITIONS	TL750M12C, TL751M12C TL750M12Q, TL751M12Q			UNIT
		MIN	TYP	MAX	
Output voltage	$T_J = 25^\circ\text{C}$	11.88	12	12.12	V
	$T_J = \text{MIN to MAX}^\dagger$	11.76		12.24	
Input voltage regulation	$V_I = 14\text{ V to }19\text{ V}, I_O = 250\text{ mA}$		15	43	mV
	$V_I = 13\text{ V to }26\text{ V}, I_O = 250\text{ mA}$		20	78	
Ripple rejection	$V_I = 13\text{ V to }23\text{ V}, f = 120\text{ Hz}$	50	55		dB
Output voltage regulation	$I_O = 5\text{ mA to }750\text{ mA}$		30	120	mV
Dropout voltage	$I_O = 500\text{ mA}$			0.5	V
	$I_O = 750\text{ mA}$			0.6	
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		1000		μV
Bias current	$I_O = 750\text{ mA}$		60	75	mA
	$I_O = 10\text{ mA}$			5	
Bias current (TL751Mxx only)	$\overline{\text{ENABLE}} V_{IH} \geq 2\text{ V}$			200	μA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

NOTE 2: Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1- μF capacitor across the input and a 10- μF tantalum capacitor on the output with equivalent series resistance within the guidelines shown in Figure 3.



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electrical characteristics, $V_I = 14\text{ V}$, $I_O = 300\text{ mA}$, $\overline{\text{ENABLE}}$ at 0 V , $T_J = 25^\circ\text{C}$ (unless otherwise noted) (see Note 2)

PARAMETER	TEST CONDITIONS		TL751M05M			UNIT
			MIN	TYP	MAX	
Output voltage	$V_I = 6\text{ V to }26\text{ V}$, $I_O = 0\text{ mA to }480\text{ mA}$	$T_J = 25^\circ\text{C}$ $T_J = -55^\circ\text{C to }125^\circ\text{C}$	4.95	5	5.05	V
			4.9		5.1	
Input voltage regulation	$V_I = 9\text{ V to }16\text{ V}$, $I_O = 250\text{ mA}$			10	25	mV
	$V_I = 6\text{ V to }26\text{ V}$, $I_O = 250\text{ mA}$			12	50	
Ripple rejection	$V_I = 8\text{ V to }18\text{ V}$, $f = 120\text{ Hz}$		50*	55		dB
Output voltage regulation	$I_O = 5\text{ mA to }480\text{ mA}$			20	50	mV
Dropout voltage	$I_O = 480\text{ mA}$				0.5	V
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$			500		μV
Bias current	$I_O = 480\text{ mA}$			60	75	mA
	$I_O = 10\text{ mA}$				5	
	$\overline{\text{ENABLE}} V_{IH} \geq 2\text{ V}$				200	μA

* This parameter is not production tested.

NOTE 2: Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a $0.1\text{-}\mu\text{F}$ capacitor across the input and a $10\text{-}\mu\text{F}$ tantalum capacitor on the output with equivalent series resistance within the guidelines shown in Figure 3.

electrical characteristics, $V_I = 14\text{ V}$, $I_O = 300\text{ mA}$, $\overline{\text{ENABLE}}$ at 0 V , $T_J = 25^\circ\text{C}$ (unless otherwise noted) (see Note 2)

PARAMETER	TEST CONDITIONS		TL751M12M			UNIT
			MIN	TYP	MAX	
Output voltage	$V_I = 13\text{ V to }26\text{ V}$, $I_O = 0\text{ mA to }480\text{ mA}$	$T_J = 25^\circ\text{C}$ $T_J = -55^\circ\text{C to }125^\circ\text{C}$	11.88	12	12.12	V
			11.76		12.24	
Input voltage regulation	$V_I = 14\text{ V to }19\text{ V}$, $I_O = 250\text{ mA}$			15	43	mV
	$V_I = 13\text{ V to }26\text{ V}$, $I_O = 250\text{ mA}$			20	78	
Ripple rejection	$V_I = 13\text{ V to }23\text{ V}$, $f = 120\text{ Hz}$		50*	55		dB
Output voltage regulation	$I_O = 5\text{ mA to }480\text{ mA}$			30	120	mV
Dropout voltage	$I_O = 480\text{ mA}$				0.5	V
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$			1000		μV
Bias current	$I_O = 480\text{ mA}$			60	75	mA
	$I_O = 10\text{ mA}$				5	
	$\overline{\text{ENABLE}} V_{IH} \geq 2\text{ V}$				200	μA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

NOTE 2: Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a $0.1\text{-}\mu\text{F}$ capacitor across the input and a $10\text{-}\mu\text{F}$ tantalum capacitor on the output with equivalent series resistance within the guidelines shown in Figure 3.



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electrical characteristics, $V_I = 14\text{ V}$, $I_O = 300\text{ mA}$, $\overline{\text{ENABLE}}$ at 0 V, $T_J = 25^\circ\text{C}$ (unless otherwise noted) (see Note 2)

PARAMETER	TEST CONDITIONS	TL750M05Y			UNIT
		MIN	TYP	MAX	
Output voltage			5		V
Input voltage regulation	$V_I = 9\text{ V to }16\text{ V}$, $I_O = 250\text{ mA}$		10		mV
	$V_I = 6\text{ V to }26\text{ V}$, $I_O = 250\text{ mA}$		12		
Ripple rejection	$V_I = 8\text{ V to }18\text{ V}$, $f = 120\text{ Hz}$		55		dB
Output voltage regulation	$I_O = 5\text{ mA to }750\text{ mA}$		20		mV
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		500		μV
Bias current	$I_O = 750\text{ mA}$		60		mA

NOTE 2: Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1- μF capacitor across the input and a 10- μF tantalum capacitor on the output with equivalent series resistance within the guidelines shown in Figure 3.

electrical characteristics, $V_I = 14\text{ V}$, $I_O = 300\text{ mA}$, $\overline{\text{ENABLE}}$ at 0 V, $T_J = 25^\circ\text{C}$ (unless otherwise noted) (see Note 2)

PARAMETER	TEST CONDITIONS	TL750M08Y			UNIT
		MIN	TYP	MAX	
Output voltage			8		V
Input voltage regulation	$V_I = 10\text{ V to }17\text{ V}$, $I_O = 250\text{ mA}$		12		mV
	$V_I = 9\text{ V to }26\text{ V}$, $I_O = 250\text{ mA}$		15		
Ripple rejection	$V_I = 11\text{ V to }21\text{ V}$, $f = 120\text{ Hz}$		55		dB
Output voltage regulation	$I_O = 5\text{ mA to }750\text{ mA}$		24		mV
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		500		μV
Bias current	$I_O = 750\text{ mA}$		60		mA

NOTE 2: Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1- μF capacitor across the input and a 10- μF tantalum capacitor on the output with equivalent series resistance within the guidelines shown in Figure 3.

electrical characteristics, $V_I = 14\text{ V}$, $I_O = 300\text{ mA}$, $\overline{\text{ENABLE}}$ at 0 V, $T_J = 25^\circ\text{C}$ (unless otherwise noted) (see Note 2)

PARAMETER	TEST CONDITIONS	TL750M10Y			UNIT
		MIN	TYP	MAX	
Output voltage			10		V
Input voltage regulation	$V_I = 12\text{ V to }18\text{ V}$, $I_O = 250\text{ mA}$		15		mV
	$V_I = 11\text{ V to }26\text{ V}$, $I_O = 250\text{ mA}$		20		
Ripple rejection	$V_I = 13\text{ V to }23\text{ V}$, $f = 120\text{ Hz}$		55		dB
Output voltage regulation	$I_O = 5\text{ mA to }750\text{ mA}$		30		mV
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		1000		μV
Bias current	$I_O = 750\text{ mA}$		60		mA

NOTE 2: Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1- μF capacitor across the input and a 10- μF tantalum capacitor on the output with equivalent series resistance within the guidelines shown in Figure 3.



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TL751M12Y electrical characteristics, $V_I = 14\text{ V}$, $I_O = 300\text{ mA}$, $\overline{\text{ENABLE}}$ at 0 V , $T_J = 25^\circ\text{C}$ (unless otherwise noted) (see Note 2)

PARAMETER	TEST CONDITIONS	TL750M12Y			UNIT
		MIN	TYP	MAX	
Output voltage			12		V
Input voltage regulation	$V_I = 14\text{ V to }19\text{ V}$, $I_O = 250\text{ mA}$		15		mV
	$V_I = 13\text{ V to }26\text{ V}$, $I_O = 250\text{ mA}$		20		
Ripple rejection	$V_I = 13\text{ V to }23\text{ V}$, $f = 120\text{ Hz}$		55		dB
Output voltage regulation	$I_O = 5\text{ mA to }750\text{ mA}$		30		mV
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		1000		μV
Bias current	$I_O = 750\text{ mA}$		60		mA

NOTE 2: Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a $0.1\text{-}\mu\text{F}$ capacitor across the input and a $10\text{-}\mu\text{F}$ tantalum capacitor on the output with equivalent series resistance within the guidelines shown in Figure 3.

PARAMETER MEASUREMENT INFORMATION

The TL751Mxx is a low-dropout regulator. This means that the capacitance loading is important to the performance of the regulator because it is a vital part of the control loop. The capacitor value and the equivalent series resistance (ESR) both affect the control loop and must be defined for the load range and the temperature range. Figures 3 and 4 can establish the capacitance value and ESR range for the best regulator performance.

Figure 3 shows the recommended range of ESR for a given load with a $10\text{-}\mu\text{F}$ capacitor on the output. This figure also shows a maximum ESR limit of $2\ \Omega$ and a load-dependent minimum ESR limit.

For applications with varying loads, the lightest load condition should be chosen since it is the worst case. Figure 4 shows the relationship of the reciprocal of ESR to the square root of the capacitance with a minimum capacitance limit of $10\ \mu\text{F}$ and a maximum ESR limit of $2\ \Omega$. This figure establishes the amount that the minimum ESR limit shown in Figure 3 can be adjusted for different capacitor values. For example, where the minimum load needed is 200 mA , Figure 4 suggests an ESR range of $0.8\ \Omega$ to $2\ \Omega$ for $10\ \mu\text{F}$. Figure 4 shows that changing the capacitor from $10\ \mu\text{F}$ to $400\ \mu\text{F}$ can change the ESR minimum by greater than $3/0.5$ (or 6). Therefore, the new minimum ESR value is $0.8/6$ (or $0.13\ \Omega$). This now allows an ESR range of $0.13\ \Omega$ to $2\ \Omega$, achieving an expanded ESR range by using a larger capacitor at the output. For better stability in low-current applications, a small resistance placed in series with the capacitor (see Table 1) is recommended, so that ESRs better approximate those shown in Figures 3 and 4.



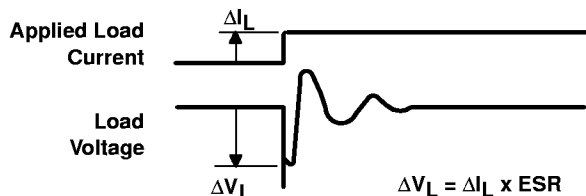
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PARAMETER MEASUREMENT INFORMATION

Table 1. Compensation for Increased Stability at Low Currents

MANUFACTURER	CAPACITANCE	ESR TYP	PART NUMBER	ADDITIONAL RESISTANCE
AVX	15 μF	0.9 Ω	TAJB156M010S	1 Ω
KEMET	33 μF	0.6 Ω	T491D336M010AS	0.5 Ω



OUTPUT CAPACITOR
EQUIVALENT SERIES RESISTANCE (ESR)
vs
LOAD CURRENT RANGE

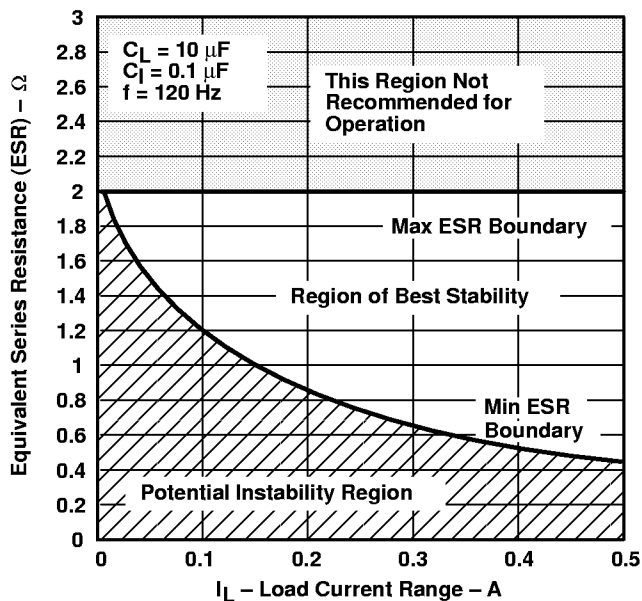


Figure 3

STABILITY
vs
EQUIVALENT SERIES RESISTANCE (ESR)

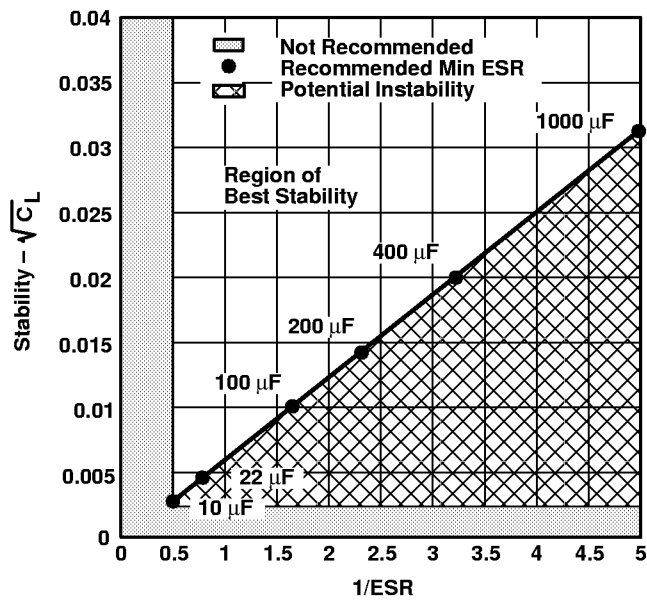


Figure 4

TYPICAL CHARACTERISTICS

Table of Graphs

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Transient input voltage vs Time		5
Output voltage vs Input voltage		6
Input current vs Input voltage	$I_O = 10\text{ mA}$	7
	$I_O = 100\text{ mA}$	8
Dropout voltage vs Output current		9
Quiescent current vs Output current		10
Load transient response		11
Line transient response		12

TRANSIENT INPUT VOLTAGE
vs
TIME

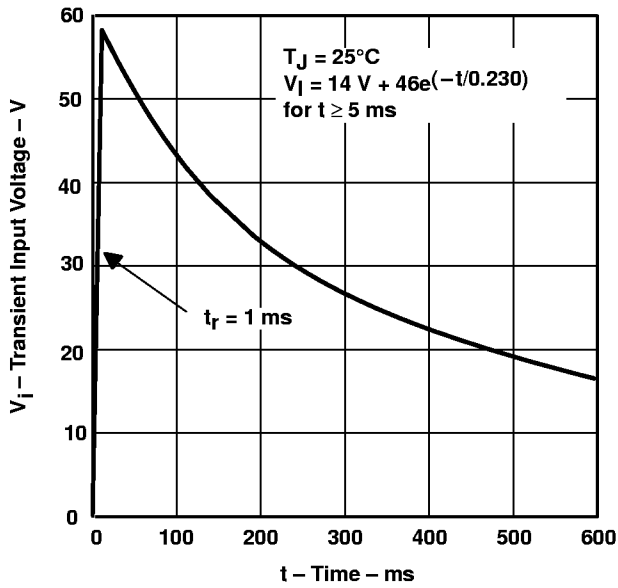


Figure 5

OUTPUT VOLTAGE
vs
INPUT VOLTAGE

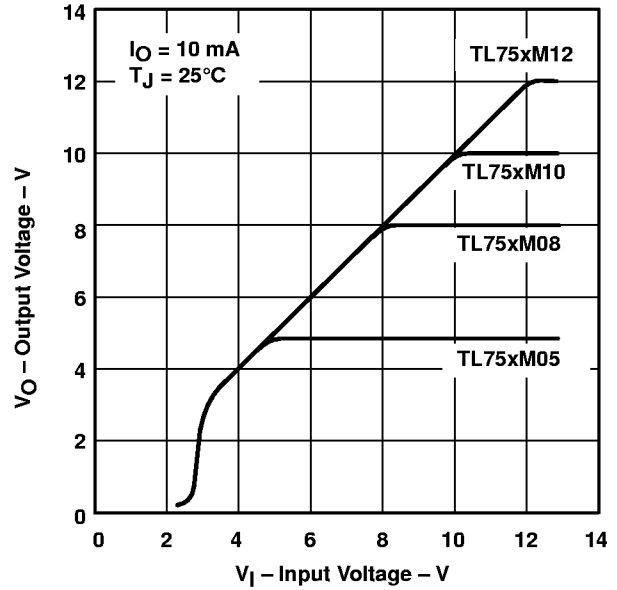
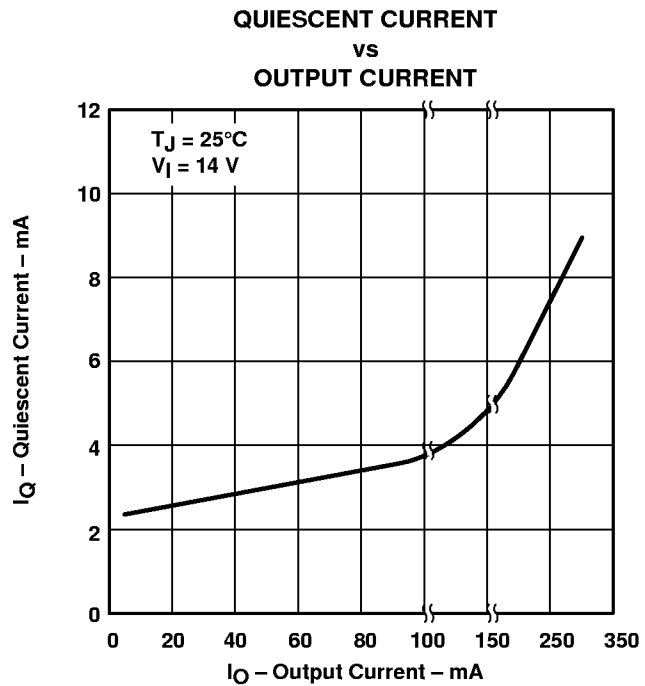
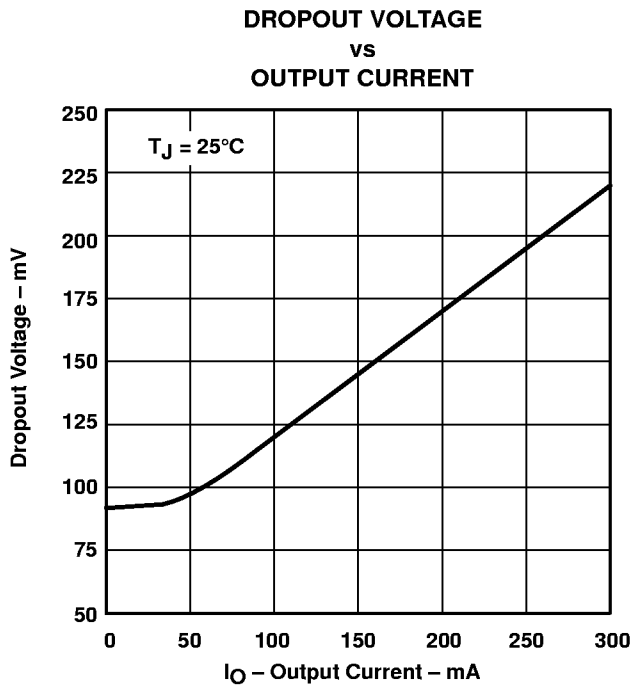
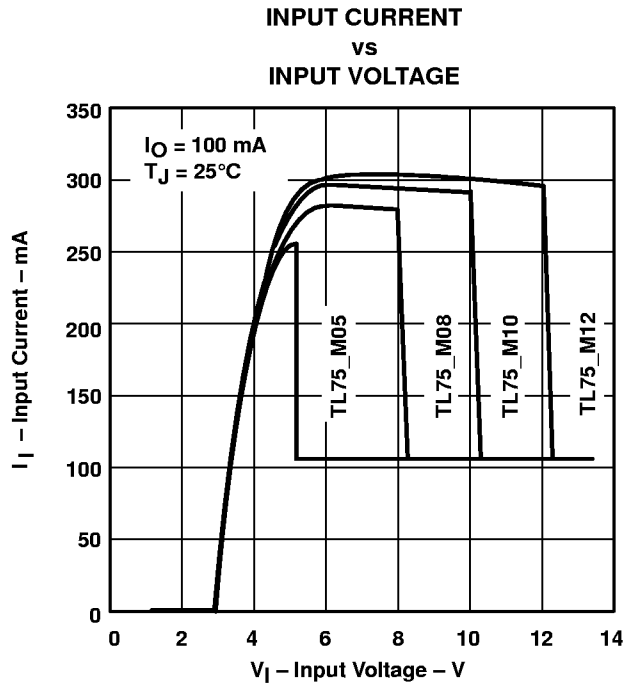
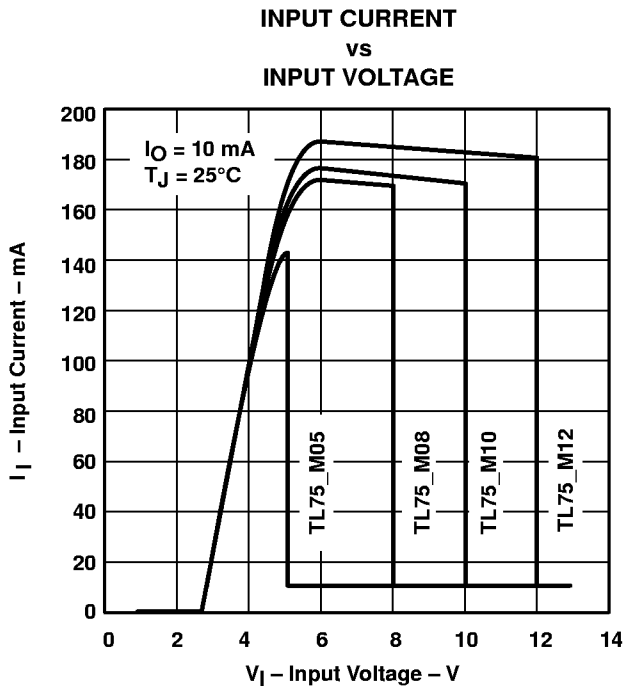


Figure 6

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TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

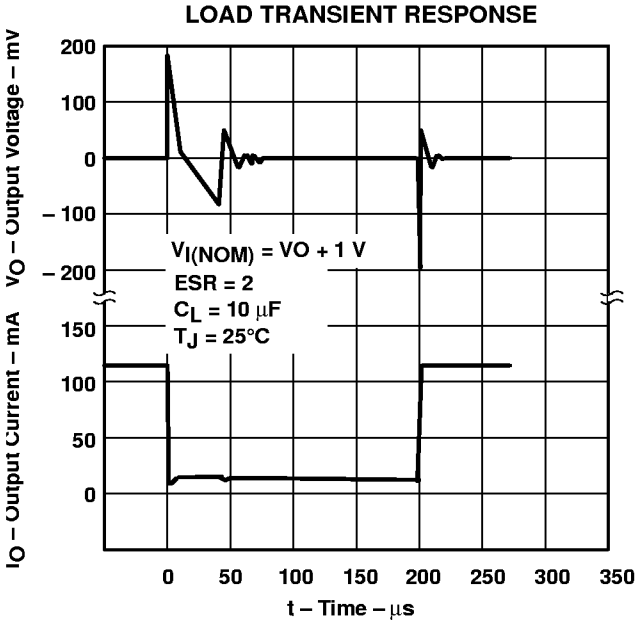


Figure 11

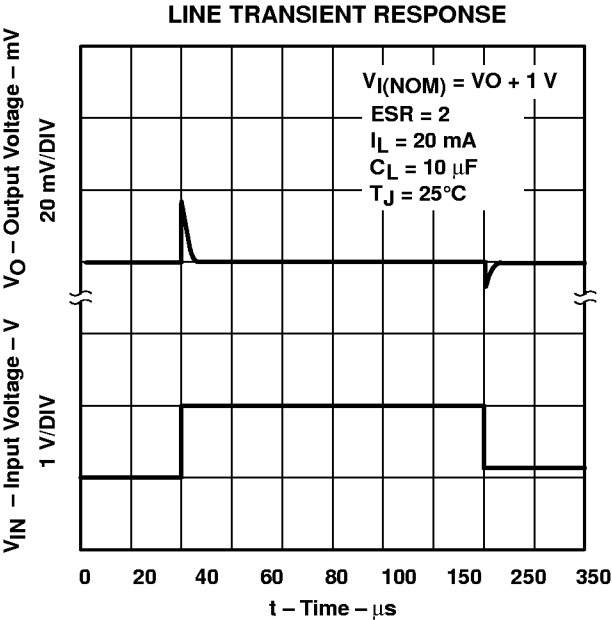


Figure 12